





PATENT NUMBER

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O.I.P.E. SCANNED WAS

PATENT DATE

APPLICATION NO. CONT/PRIOR CLASS SUBCLASS ART UNIT EXAMINER Sim Konc 09/808162 438 2812 DF

APPLICANTS

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Method of fabricating a semiconductor device

TITLE

PTO-2040 12/99

ISSUING CLASSIFICATION									
ORIGINA	AL	CROSS REFERENCE(S)							
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)						
INTERNATIONAL CLASSIFICATION									
			Continued on Issue Slip Inside File Jacket						

TERMINAL		DRAWINGS		CLAIMS ALLOWED		
L.J DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
The term of this patent		!-	·	NOTICE OF ALLOWANCE MAILED		
subsequent to (date) has been disclaimed.	(Assistant Examiner) (Date)					
The term of this patent shall not extend beyond the expiration date						
of U.S Patent. No.				ISSUE FEE		
	·			Amount Due	Date Paid	
	(Primary Examiner) (Date)					
The terminalmonths of this patent have been disclaimed.				ISSUE BA	TCH NUMBER	
	(Legal Instruments Examiner) (Date)					
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